

# TLP283,TLP283-4

## PROGRAMMABLE CONTROLLERS

AC adapters for PDAs/ on-board power supplies  
I/O interface boards

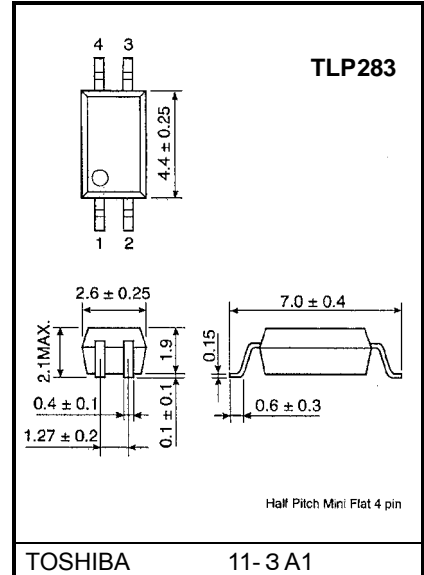
TLP283 and TLP283-4 is a very small and thin coupler,suitable for surface mount assembly in applications such as on-board power supplies,programmable controllers.

TLP283 and TLP283-4 consist of photo transistor,optically coupled to a gallium arsenide infrared emitting diode.

- Collector-Emitter Voltage : 100 V (MIN)
- Current Transfer Ratio : 100% (MIN)@IF=1mA
- 1 Pulse delay time(Note 1) : 100us(MAX)@IF=1mA,RL=10kΩ
- Isolation Voltage : 2500 Vrms (MIN)
- UL Recognized : UL1577 , File No. E67349

Note 1 : 1 Pulse delay time = tON+tOFF

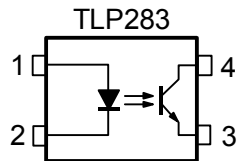
Unit in mm



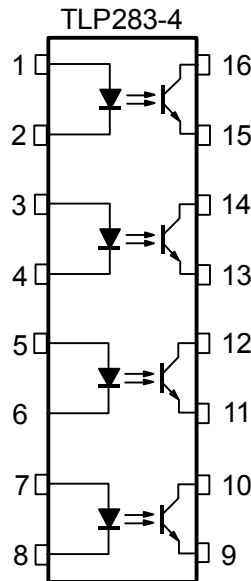
TOSHIBA 11-3 A1

Weight: 0.05 g

## PIN CONFIGURATION(Top view)

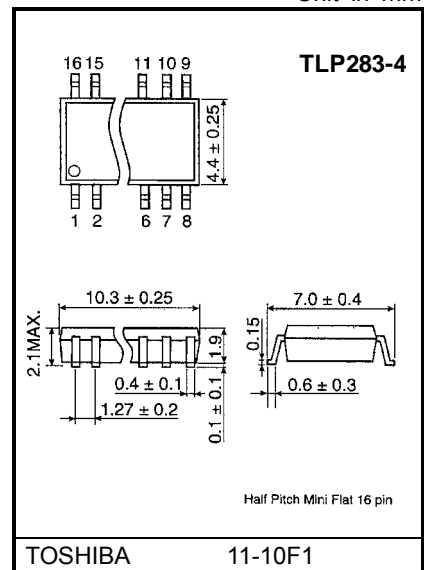


1:ANODE  
2:CATHODE  
3:EMITTER  
4:COLLECTOR



1,3,5,7 :ANODE  
2,4,6,8 :CATHODE  
9,11,13,15 :EMITTER  
10,12,14,16 :COLLECTOR

Unit in mm



TOSHIBA 11-10F1

Weight: 0.19 g

## MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING		UNIT
			TLP283	TLP283-4	
LED	Forward Current	$I_F$	50		mA
	Forward Current Derating	$\Delta I_F / ^\circ\text{C}$	-0.7 (Ta $\geq$ 53°C)	-0.5 (Ta $\geq$ 25°C)	mA / °C
	Pulse Forward Current	$I_{FP}$	1		A
	Reverse Voltage	$V_R$	5		V
	Junction Temperature	$T_j$	125		°C
DETECTOR	Collector-Emitter Voltage	$V_{CEO}$	100		V
	Emitter-Collector Voltage	$V_{ECO}$	7		V
	Collector Current	$I_C$	50		mA
	Collector Power Dissipation (1 Circuit)	$P_C$	150	100	mW
	Collector Power Dissipation Derating (Ta $\geq$ 25°C) (1 Circuit)	$\Delta P_C / ^\circ\text{C}$	-1.5	-1.0	mW / °C
	Junction Temperature	$T_j$	125		°C
Operating Temperature Range		$T_{opr}$	-55~100		°C
Storage Temperature Range		$T_{stg}$	-55~125		°C
Lead Soldering Temperature		$T_{sol}$	260 (10s)		°C
Total Package Power Dissipation (1 Circuit)		$P_T$	200	170	mW
Total Package Power Dissipation Derating (Ta $\geq$ 25°C) (1 Circuit)		$\Delta P_T / ^\circ\text{C}$	-2.0	-1.7	mW / °C
Isolation Voltage (Note2)		$BV_S$	2500(AC, 1min, R.H. $\leq$ 60%)		Vrms

(Note2) Device considered a two terminal device : LED side pins shorted together and DETECTOR side pins shorted together.

## INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	$V_F$	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
	Reverse Current	$I_R$	$V_R = 5 \text{ V}$	—	—	10	$\mu\text{A}$
	Capacitance	$C_T$	$V = 0, f = 1 \text{ MHz}$	—	30	—	pF
DETECTOR	Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 0.5 \text{ mA}$	100	—	—	V
	Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	$I_E = 0.1 \text{ mA}$	7	—	—	V
	Collector Dark Current (Note3)	$I_{CEO}$	$V_{CE} = 48 \text{ V},$ Ambient Light Below (100 lx)	—	0.01 (2)	0.1 (10)	$\mu\text{A}$
			$V_{CE} = 48 \text{ V}, T_a = 85^\circ\text{C}$ Ambient Light Below (100 lx)	—	2 (4)	50 (50)	$\mu\text{A}$
Capacitance (Collector to Emitter)	$C_{CE}$	$V = 0, f = 1 \text{ MHz}$	—	10	—	pF	

(Note3) Because of the construction, leak current might be increased by ambient light. Please use photocoupler with less ambient light.

**COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Current Transfer Ratio	$I_C / I_F$	$I_F = 1 \text{ mA}, V_{CE} = 5 \text{ V}$	100	—	400	%
Saturated CTR	$I_C / I_F (\text{sat})$	$I_F = 1 \text{ mA}, V_{CE} = 0.4 \text{ V}$	50	—	—	%
Collector-Emitter Saturation Voltage	$V_{CE (\text{sat})}$	$I_C = 0.2 \text{ mA}, I_F = 1 \text{ mA}$	—	0.2	0.4	V
Off-State Collector Current	$I_C (\text{off})$	$V_F = 0.7 \text{ V}, V_{CE} = 48 \text{ V}$	—	—	10	$\mu\text{A}$

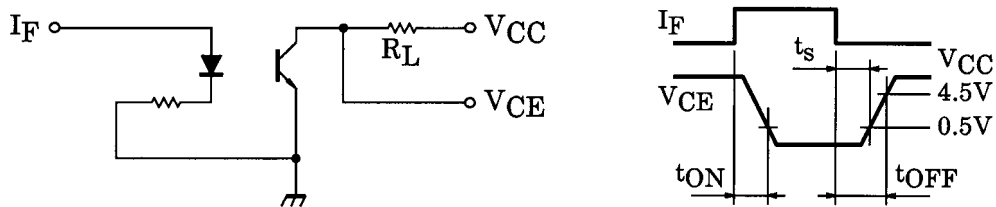
**ISOLATION CHARACTERISTICS (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance (Input to Output)	$C_S$	$V_S = 0 \text{ V}, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation Resistance	$R_S$	$V_S = 500 \text{ V}, \text{R.H.} \leq 60\%$	$5 \times 10^{10}$	$10^{14}$	—	$\Omega$
Isolation Voltage	$BV_S$	AC, 1 minute	2500	—	—	Vrms
		AC, 1 second, in OIL	—	5000	—	
		DC, 1 minute, in OIL	—	5000	—	Vdc

**SWITCHING CHARACTERISTICS (Ta = 25°C)**

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Turn-On Time	$t_{ON}$	$V_{CC} = 5 \text{ V}, I_F = 1 \text{ mA}$ $R_L = 10 \text{ k}\Omega$	—	7.5	20	$\mu\text{s}$
Turn-Off Time	$t_{OFF}$		—	70	90	
1 Pulse delay time	$t_{ON} + t_{OFF}$		—	80	100	

(Fig.1) SWITCHING TIME TEST CIRCUIT



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000707EBC

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